

Quasiparticle scattering rate in overdoped superconducting cuprates

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We calculate the quasiparticle scattering rate in the superconducting state of the overdoped cuprates, in the context of the Eliashberg formalism for a Fermi liquid with strong van Hove singularities close to the chemical potential. For a $d_{x^2-y^2}$ superconducting gap, we demonstrate analytically that the scattering rate is linear in the maximum of temperature or energy, but with different intercepts and momentum dependence, thus extending our earlier results on the normal state. We discuss our results in view of angle-resolved photoemission experiments. We also comment on the case of a s-wave gap.

The nature of the carriers in the cuprates is an important question, which has been discussed and debated extensively. The availability of relevant experimental data over the years, and in particular angle-resolved photoemission (ARPES), should be helpful in the effort towards achieving a better understanding of this question.

Here, we look at a characteristic one-particle property, relevant to ARPES. We obtain analytically the scattering rate in the superconducting state for a Fermi liquid with strong density of states peaks - van-Hove singularities (vHs) in 2-D - located close to the chemical potential μ . Incidentally, this model does not apply to the underdoped cuprates, as there is no indication that a Fermi liquid description is appropriate. The *qualitative* nature of our results does not depend on the doping level, for as long as we remain within the realm of Fermi liquid theory. Precise numerical calculations can yield the quantitative dependence of the theory on the doping etc. A review of related work in the frame of the so-called van-Hove scenario has been given in¹. The pinning of the vHs close to μ seems to be a plausible explanation for the common characteristics of a good many cuprates, whose van-Hove singularities are located between 10-30 meV below the Fermi surface², as ARPES experiments have shown. A review of some calculations yielding the pinning of the vHs close to μ appears in³. The present work extends our results for the normal state, obtained in^{3,4}, to the superconducting state. The analysis presented below can also be done in the frame of a weak-coupling BCS-type approach. We opt for the intermediate to strong-coupling Eliashberg approach, which is relevant for the cuprates. *Qualitatively*, i.e. as far as power laws etc. are concerned in terms of energy and temperature, the answers are the same for the two approaches.

We consider a generic dispersion appropriate for the cuprates, of the type t, t', t''

$$\epsilon_k = -2t(\cos k_x + \cos k_y) - 4t' \cos k_x \cos k_y - 2t''(\cos 2k_x + \cos 2k_y) . \quad (1)$$

This dispersion generates strong vHs located at the points $(\pm\pi, 0), (0, \pm\pi)$.

In the context of the Eliashberg formalism, the Green's function in the superconducting state is

$$G(k, \epsilon_n) = \frac{i\epsilon_n Z(k, \epsilon_n) + \epsilon_k - \mu + X(k, \epsilon_n)}{P(k, \epsilon_n)} , \quad (2)$$

with $\epsilon_n = (2n + 1)\pi T$ and

$$P(k, \epsilon_n) = [i\epsilon_n Z(k, \epsilon_n)]^2 - [\epsilon_k - \mu + X(k, \epsilon_n)]^2 - D^2(k, \epsilon_n) . \quad (3)$$

The renormalization $Z(k, \epsilon_n)$, the energy shift $X(k, \epsilon_n)$ and the (singlet) superconducting gap parameter $D(k, \epsilon_n)$ are given by the Eliashberg equations

$$i\epsilon_n[1 - Z(k, \epsilon_n)] = T \sum_{p, \epsilon_{n'}} \frac{V(k - p, \epsilon_n - \epsilon_{n'}) i\epsilon_{n'} Z(p, \epsilon_{n'})}{P(p, \epsilon_{n'})} , \quad (4)$$

$$X(k, \epsilon_n) = T \sum_{p, \epsilon_{n'}} \frac{V(k - p, \epsilon_n - \epsilon_{n'}) [\epsilon_p - \mu + X(p, \epsilon_{n'})]}{P(p, \epsilon_{n'})} , \quad (5)$$

and

$$D(k, \epsilon_n) = T \sum_{p, \epsilon_{n'}} \frac{V_p(k-p, \epsilon_n - \epsilon_{n'}) D(p, \epsilon_{n'})}{P(p, \epsilon_{n'})} . \quad (6)$$

$V(q, \omega_n)$ generates the diagonal self-energy - c.f. below - and $V_p(q, \omega_n)$ is the pairing potential. These potentials depend on the quasiparticle Green's function through screening. In general, e.g. for spin dependent interactions etc., these two potentials differ.

The diagonal self-energy is given by

$$\Sigma(k, \epsilon_n) = i\epsilon_n[1 - Z(k, \epsilon_n)] + X(k, \epsilon_n) = T \sum_{p, \epsilon_{n'}} V(k-p, \epsilon_n - \epsilon_{n'}) G(p, \epsilon_{n'}) . \quad (7)$$

Our derivation relies on this last equation, which is valid quite generally in the frame of a Baym-Kadanoff (BK) conserving approximation⁵, irrespectively of the specific Hamiltonian and approximation thereof³.

The quasiparticle scattering rate is twice the imaginary part of $\Sigma(k, \epsilon) = \Sigma_1(k, \epsilon) + i\Sigma_2(k, \epsilon)$. It can easily be shown⁶ that $Im\Sigma(k, \epsilon)$ is given by the following formula for real energy at finite temperature :

$$\Sigma_2^R(k, \epsilon) = \sum_q \int_{-\infty}^{\infty} \frac{d\omega}{2\pi} ImG^R(k-q, \epsilon-\omega) ImV^R(q, \omega) \{ \coth(\omega/2T) + \tanh((\epsilon-\omega)/2T) \} . \quad (8)$$

We have

$$ImG^R(k, \epsilon) = B(k, \epsilon) Im\left\{ \frac{1}{a-b-D} \right\} + F(k, \epsilon) Re\left\{ \frac{1}{a-b-D} \right\} . \quad (9)$$

Here $a = \epsilon Z(k, \epsilon)$, $b = \epsilon_k - \mu + X(k, \epsilon)$, $D = D(k, \epsilon)$, $B(k, \epsilon) = Re\left\{ \left(\frac{a+b}{a+b+D} \right)^R \right\}$ and $F(k, \epsilon) = Im\left\{ \left(\frac{a+b}{a+b+D} \right)^R \right\}$. Note that $a-b = G^{-1}(k, \epsilon)$ in the normal state.

We see that the factor

$$F(k, \epsilon) = \frac{f_2(k, \epsilon) D_1(k, \epsilon) - f_1(k, \epsilon) D_2(k, \epsilon)}{[f_1(k, \epsilon) + D_1(k, \epsilon)]^2 + [f_2(k, \epsilon) + D_2(k, \epsilon)]^2} , \quad (10)$$

with $f_1(k, \epsilon) = Ref(k, \epsilon)$, $f_2(k, \epsilon) = Imf(k, \epsilon)$, $f(k, \epsilon) = \epsilon Z(k, \epsilon) + \epsilon_k - \mu + X(k, \epsilon)$, and $D(k, \epsilon) = D_1(k, \epsilon) + iD_2(k, \epsilon)$. This term is proportional to the gap function, and hence it gives a negligibly small contribution upon summation over the Brillouin zone for a $d_{x^2-y^2}$ gap $D_i(k, \epsilon) \simeq D_{io}(\epsilon) d(k)$, $d(k) = \cos k_x - \cos k_y$. So we can omit the second term in the r.h.s. of eq. (9). This is not the case for a s -wave gap though, where this term should be kept.

$B(k, \epsilon)$ is given by

$$B(k, \epsilon) = \frac{f_1^2(k, \epsilon) + f_2^2(k, \epsilon) + D_1(k, \epsilon) f_1(k, \epsilon) + D_2(k, \epsilon) f_2(k, \epsilon)}{[f_1(k, \epsilon) + D_1(k, \epsilon)]^2 + [f_2(k, \epsilon) + D_2(k, \epsilon)]^2} . \quad (11)$$

We can make the approximation

$$Im\left\{ \frac{1}{a-b-D} \right\} \simeq -\pi\delta(\epsilon + \mu - \epsilon_k - \Sigma_1(k, \epsilon) - D_1(k, \epsilon)) . \quad (12)$$

This approximation was made in^{4,3}. Setting $ImG^R(k, \epsilon)$ equal to a delta function is a reasonable approximation for this purpose, in view of the typical sharp spike feature of $ImG^R(k, \epsilon)$ shown in³ - c.f. fig. 1 therein. This is in the frame of numerical self-consistent FLEX calculations⁷. Further, numerically $ImG^R(k, \epsilon)$ is *very small* compared to the band energy for small couplings, and the difference of $Im\Sigma(k, \epsilon)$, as seen in our numerical calculation, for small and large coupling constants is mostly *quantitative* rather than qualitative. Moreover, the approximation of eq. (12) has also been used in the context of the electron-phonon problem in⁶ (c.f. the equation right before eq. (21.29) therein).

Further, omitting terms of order $[\omega^2 \partial_\epsilon^2 Re\Sigma(k, \epsilon)]$ and $[\omega^2 \partial_\epsilon^2 ReD(k, \epsilon)]$ we obtain

$$\Sigma_2^R(k, \epsilon) \simeq -\frac{1}{2} \sum_q B(k-q, \epsilon - w_{k-q, \epsilon}) ImV^R(q, w_{k-q, \epsilon}) \{ \coth(w_{k-q, \epsilon}/2T) + \tanh((\epsilon - w_{k-q, \epsilon})/2T) \} , \quad (13)$$

where

$$w_{k, \epsilon} = \frac{\epsilon + \mu - \epsilon_k - \Sigma_1(k, \epsilon) - D_1(k, \epsilon)}{1 - \partial_\epsilon \Sigma_1(k, \epsilon) - \partial_\epsilon D_1(k, \epsilon)} . \quad (14)$$

We write

$$ImV^R(q, x) = \sum_{n=0}^{\infty} \frac{V_q^{(2n+1)}(0) x^{2n+1}}{(2n+1)!} , \quad (15)$$

where $V_q^{(n)}(0)$ is the n -th derivative of $ImV^R(q, \omega = 0)$ with respect to ω . Eq. (15) is true in the context of a BK approximation, and $V(q, \omega)$ may contain vertex corrections. E.g. for RPA and FLEX we see that the overall behavior of ImV closely follows the carrier susceptibility(-ies) $\chi_o(q, \omega)$, which we assume to be a regular function of ω , as

$$ImV(q, \omega) = \sum_i Im\chi_{oi}(q, \omega) |\varepsilon_i(q, \omega)|^2 . \quad (16)$$

$Im\chi_o$ is odd in ω , while $|\varepsilon|^2$ is even, with $\varepsilon(q, \omega)$ the dielectric function. In the FLEX approximation, i = spin, charge, in RPA i = charge. In other BK approximations, e.g. c.f.⁸, eq. (15) is valid as well, with $ImV(q, \omega)$ obeying an equation similar to eq. (16).

The derivation given below for the linear in energy and temperature behavior of $\Sigma_2(k, \epsilon; T)$ is generic. It relies essentially on a large coefficient for the linear in energy term of ImV - i.e. of $Im\chi_o$ etc. - and the presence of van-Hove singularities *near* the Fermi surface. The result holds *regardless* of the dimensionality of the system. However, it is important that a significant part of the spectral weight be included in the strong peaks of the density of states lying close to μ , a situation which is particularly favored in 2-D.

For *sufficiently small* $V_q^{(n)}(0)$, $\forall n > 1$, we obtain

$$\sum_q V_{k-q}^{(1)}(0) w_{k-q, \epsilon} \gg \sum_q \sum_{n=1}^{\infty} \frac{V_{k-q}^{(2n+1)}(0) (w_{k-q, \epsilon})^{2n+1}}{(2n+1)!} . \quad (17)$$

This relation is valid for $w_{k-q, \epsilon} < \epsilon_c$, where the latter is the characteristic energy beyond which the infinite sum on the right becomes comparable to the $V_q^{(1)}$ term (ϵ_c can be estimated by equating the lhs and rhs of eq.(17) with $n = 1$ only). We constrain ourselves to the regime where eq. (17) is valid, as it is precisely this regime which gives the linear in $\max\{T, \epsilon\}$ dependence of Σ_2 in the normal state^{4,3}.

Then we obtain

$$\Sigma_2(k, \epsilon) \simeq -\frac{1}{2} \sum_q V_q^{(1)}(0) B(k - q, \epsilon - w_{k-q, \epsilon}) w_{k-q, \epsilon} \{ \coth(w_{k-q, \epsilon}/2T) + \tanh((\epsilon - w_{k-q, \epsilon})/2T) \} . \quad (18)$$

The sum over q is dominated by the (extended) van Hove momenta q_o in the vicinity of $(\pm\pi, 0)$ and $(0, \pm\pi)$.

Now notice that the following inequalities are satisfied:

$$\epsilon + \mu - \epsilon_{k-q_o} > 0 , \quad (19)$$

$$Re\Sigma(k - q_o, \epsilon) < 0 . \quad (20)$$

The former is true for all momenta k in the Brillouin zone except (possibly) for $k \simeq 0$. The latter is seen to be true for e.g. $0 \leq \epsilon < 4t$ from numerical FLEX calculations - c.f.^{3,7}. Combining the two we get

$$\epsilon + \mu - \epsilon_{k-q_o} - Re\Sigma(k - q_o, \epsilon) > 0 . \quad (21)$$

Also,

$$\partial_\epsilon \Sigma_1(k, \epsilon) < 0 , \quad (22)$$

and

$$|\partial_\epsilon \Sigma_1(k, \epsilon)| \gg |\partial_\epsilon D_1(k, \epsilon)| , \quad (23)$$

for $\delta < \epsilon < \epsilon_o$ ^{3,7}, where δ is a small negative energy and $0 < \epsilon_o = O(t)$. Overall eqs. (19)-(23) yield

$$w_{k-q_o, \epsilon} > 0 . \quad (24)$$

We obtain a linear in T scattering rate in the limit $T > \epsilon, w_{k-q, \epsilon}$

$$\Sigma_2^R(k, \epsilon) \simeq -T \sum_q V_q^{(1)}(0) B(k - q, \epsilon - w_{k-q, \epsilon}) . \quad (25)$$

The coefficient of T is maximized when $k - q_o$ lies along the diagonals of the Brillouin zone, and minimized close to the vH points. This effect is of order $(D_i/f_i)^2$ though, so it does not contribute much for a small gap.

It has been known long ago - see e.g.⁹ - that the scattering rate becomes linear in T for $T > \omega_B/4$, with ω_B being the characteristic boson frequency mediating the carrier interaction. Our treatment shows that ω_B here is nothing else but the *fermionic* energy $w_{k-q_o, \epsilon}$. The results here complement our earlier normal state results in^{3,4}.

ARPES experiments^{10,11} have indicated that in the superconducting state, and, *presumably*, for $\epsilon \rightarrow 0$, the scattering rate is linear in T for k_F close to the nodal directions, but otherwise saturates to a value which increases as k_F approaches the vH points. Our result is in agreement with ARPES for k_F along the diagonals of the Brillouin zone. The reason for the off-diagonal discrepancy is not clear at present. Certainly more data, and on compounds other than BSCCO, would be helpful in clarifying this issue.

We now turn to the limit $T < \epsilon$. We note that for $\epsilon < w_{k-q, \epsilon}$ and for $w_{k-q, \epsilon} < 0$ the contributions of $\tanh$ and $\coth$ annihilate each other in the low T limit. Then, for $\epsilon > w_{k-q_o, \epsilon}$

$$\Sigma_2^R(k, \epsilon) \simeq -\frac{c_{k, \epsilon}}{2} \sum_q V_q^{(1)}(0) B(k - q, \epsilon - w_{k-q, \epsilon}) w_{k-q, \epsilon} , \quad (26)$$

where $c_{k, \epsilon} = 1 + \langle \tanh((\epsilon - w_{k-q_o, \epsilon})/2T) \rangle$ is a factor between 1 and 2. This equation yields a linear in ϵ scattering rate, if $\partial_\epsilon \Sigma_1(k - q_o, \epsilon)$ varies slowly with ϵ . Actually, assuming that $D_i^2(k, \epsilon) \ll f_i^2(k, \epsilon)$ we obtain

$$\Sigma_2^R(k, \epsilon) \simeq -\frac{2V_{q_o}^{(1)}(0)N_o c_{k, \epsilon}}{1 - \partial_\epsilon \Sigma_1(k', \epsilon)} \left\{ \epsilon + \mu - \epsilon_{k'} - \Sigma_1(k', \epsilon) - \frac{[f_1(k', w)D_{1o}(w) + f_2(k', w)D_{2o}(w)]D_{1o}(\epsilon)d^2(k')}{f_1^2(k', w) + f_2^2(k', w)} \right\} . \quad (27)$$

where $k' = k - q_o$, $w = \epsilon - w_{k-q_o, \epsilon}$ and N_o stands for the q -summation around a single vHs. We see that this expression is linear in ϵ , and that the gap-dependent term is minimized for $k - q_o$ lying along the diagonals (with the assumption that $f_i(k', w)$ vary more slowly with k' than the gap). For a s-wave gap we obtain a dependence $\epsilon - D$ instead, just from the term $w_{k-q_o, \epsilon}$ in eq. (26), and $B(k, \epsilon)$ yields an additional D contribution. These two distinct dependencies of Σ_2 on the gap are characteristic of the respective gap symmetries. Estimates of the parameters in eq. (27) cannot be easily obtained analytically, due to the complicated nature of the Eliashberg formalism. Precise numerical estimates are possible, but they are beyond the scope of the present work.

ARPES experiments in^{12,13,11,14} indicate that the scattering rate is a linear function of energy both in the superconducting and the normal state, in agreement with our results. The normal state result was obtained in^{3,4}.

Summarizing, within the Fermi liquid Eliashberg formalism, we calculate the one-particle scattering rate in the superconducting state of overdoped cuprates. We compare our findings with existing ARPES experiments. For $T < \epsilon$, the ϵ -dependence obtained is consistent with expts. For $T > \epsilon$, the T -dependence obtained agrees with expts. for k_F along the Brillouin zone diagonals.

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